

COPIED
ISSUE C 2034

U.S. UTILITY Patent Application

O.I.P.E.

PATENT DATE

11/10/94 TM

APPLICATION NO.	CONT/PRIOR	CLASS	SUBCLASS	ART UNIT	EXAMINER
99/682,151		257	58	382	D. Chiu

APPLICANTS

Martin Kondesek
Howard Bartlow
Richard Wondin

BEST AVAILABLE COPY

TITLE

Contact method for thin silicon carbide epitaxial layer and semiconductor devices formed by these methods

PTO-240
(12/89)

FILED WITH 12/10/94

(FACE)